

#### 1A LED Driver with Internal Switch

### **General Description**

**SCT2932** is a high efficiency, constant current, continuous mode inductive step-down converter, designed for driving constant current to high power (single or multiple) LED with only 4 external components. SCT2932 operates from input supply between 5V and 33V and provides an externally adjustable output current of up to 1A.

The SCT2932 is specifically designed with PFM control to enhance the efficiency up to 95%. The Output current can be modify by an external resister, and can adjusted, by applying an external control signal to the DIM pin, The DIM pin will accept a PWM waveform.

Additionally, to ensure the system reliability, SCT2932 is built-in with over temperature protection, and LED open-circuit/short-circuit protection to protect system from being damaged.

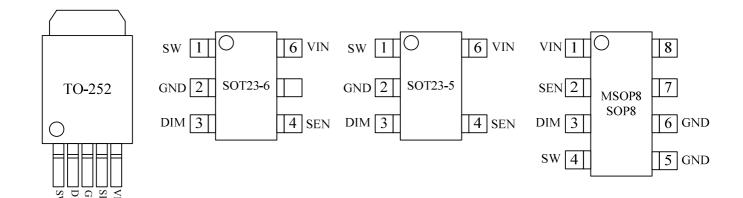
#### **Features**

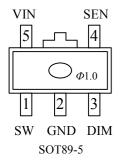
- ♦ 1A output current
- ♦ Wide input voltage range: 5V to 33V
- ♦ High efficiency (up to 95%)
- ♦ Internal NDMOS power switch
- ♦ Single pin on/off and brightness control using PWM
- ♦ Hysteretic PFM improves efficiency at light loads
- ♦ With Thermal/Soft start /LED open-short detect protection
- ♦ Only 4 External Components
- ♦ Up to 1Mhz switching frequency
- ♦ Typical 3% output current accuracy

### **Applications**

- High power LED lighting
- Automotive LED lighting
- Low voltage industrial lighting
- LED back-up lighting
- Constant Current Source

## **Package Type**





SOT23-6: SCT2932B TO252-5: SCT2932C

MSOP8 (with Thermal Pad) : SCT2932D

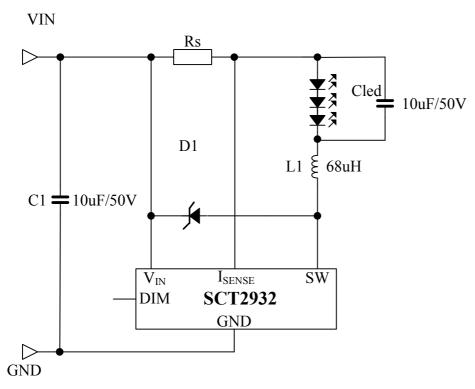
SOP8 : SCT2932E SOT89-5: SCT2932F SOT23-5: SCT2932J

## **Pin Description**

Pin Name	Pin Description
SW	Drain of NDMOS switch
GND	Ground pad
DIM	Dimming control pad
ISEN	Connect resistor RS from this pin to VIN to define nominal average
	output current
VIN	Power pad

## **Application Circuit**

# Typical applicatiom circuit



## **Absolute Maximum Ratings**

J	TEM	SYMBOL	RATING	UNIT
Supply Voltage		Vin	0-33 (40V for 0.5 sec)	V
Output Current		Іоит	1.25	A
Sustaining Volta	ige at SW pin	Vsw	-0.5~33 (40V for 0.5 sec)	V
Power	SOP8	PD	1.4	W
Dissipation *	MSOP8(thermal		1.45	
	Pad)			
	TO252		2.8	
	SOT23-6		1.2	
	SOT23-5		1.2	
	SOT89-5		1.45	]
Thermal	SOP8	Rth(j-a)	89.3	°C/W
Resistance	MSOP8(thermal	-	86.2	]
	Pad)			
	TO252		44.6	
	SOT23-6		104.2	
	SOT23-5		104.2	
	SOT89-5		86.2	
Operating	Temperature	Тор	-40°C - +85°C	$^{\circ}\mathbb{C}$
Storage	Temperature	Tsto	-55°C - +150°C	$^{\circ}$ C
Junction	Temperature	Тј-мах	150	$^{\circ}\!\mathbb{C}$

<sup>\*</sup> The PCB size is 22mm\*20mm with 2-layer PCB.

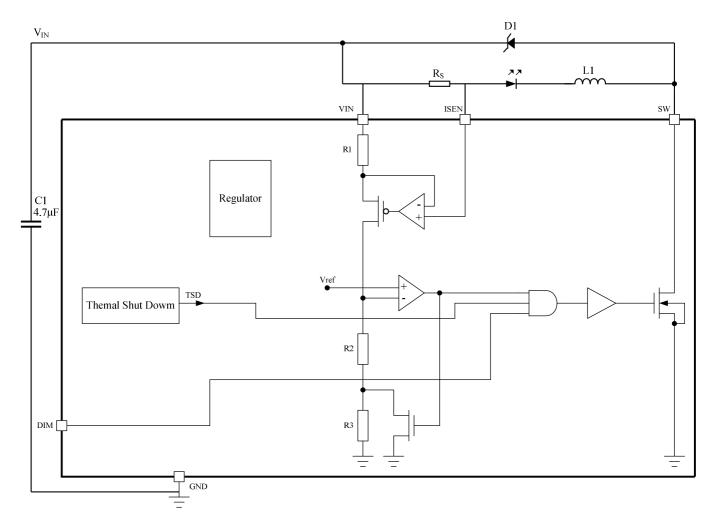
<sup>\*\*</sup> Power Dissipation depend on PCB layout .

### **Electrical Characteristics**

Test condition :  $V_{IN}=12V$ ,  $V_{OUT}=3.6V$ , L1=68uH,  $C_{IN}=C_{OUT}=10uF$ , Ta=25  $^{\circ}C$  ; unless otherwise specified.

	Symbol	Condition	min₀	typ。	Max <sub>o</sub>	unit
Item				Jr		
Operating voltage	Vin		5	-	33	V
Operating current	IIN	V <sub>IN=</sub> 5V~33V	-	1	2	mA
Output current	I <sub>OUT</sub>		-	-	1	A
Output current Accuracy	$\Delta I_{OUT}I_{OUT}$	$150\text{mA} \leq I_{\text{OUT}} \leq 1\text{A}$		±3	±5	%
Efficiency		V <sub>IN</sub> =12V, I <sub>OUT</sub> =350mA, V <sub>out</sub> =10.8V		95		%
SW Dropout voltage	$\Delta Vsw$	Iout=1A		0.5		V
Internal propagation delay	TPD		100	200	300	NS
Input voltage	VIH		3.5		5	V
	VIL				0.5	V
Sense threshold hysteresis	VSENSEHYS			±15	-	%
Mean current sense threshold voltage	VSENSE		95	100	105	mV
Switch on resistance	RDS(ON)	VIN=12V, IOUT=350mA, Vout=10.8V		0.5	1	Ω
Minimum switch 'ON' time	TONmin		100	350	450	ns
Minimum switch 'OFF'	TOFFmin		100	350	450	ns
Recommended duty cycle range oft switch	Dsw		0.2		0.8	
maximum operating frequency	Freq <sub>MAX</sub>		40		1000	KHz
Thermal Shutdown Threshold	Tsd		145	160	175	$^{\circ}\!\mathbb{C}$
Thermal Shutdown Hystersis	Tsd-hys			20		$^{\circ}\!\mathbb{C}$
Duty cycle range of PWM signal applied to DIM pin	Dutydim	PWM frequency = 1KHz	0.01		1	
Rise Time of Output current	Tr	Vout= 3.6V , I <sub>OUT=</sub> 350mA, fdim=1kHz , Dutydim=50%		20		ns
Fall Time of Output current	Tf	Vout= 3.6V , I <sub>OUT=</sub> 350mA, fdim=1kHz , Duty <sub>DIM</sub> =50%		20		ns

### **Block Diagram**



### **Device Description**

The device, in conjunction with the coil (L1) and current sense resistor (RS), forms a selfoscillating continuous-mode buck converter.

### **Device Operation** (Refer to block diagram and Figure 1 - Operating waveforms)

Operation can be best understood by assuming that the DIM pin of the device is unconnected and the voltage on this pin (VDIM) appears directly at the (+) input of the comparator.

When input voltage VIN is first applied, the initial current in L1 and RS is zero and there is no output from the current sense circuit. Under this condition, the (-) input to the comparator is at ground and its output is high. This turns MN on and switches the SW pin low, causing current to flow from VIN to ground, via RS, L1 and the LED(s). The current rises at a rate determined by VIN and L1 to produce a voltage ramp (VSENSE) across RS. The supply referred voltage VSENSE is forced across internal resistor R1 by the current sense circuit and produces a proportional current in internal resistors R2 and R3. This produces a ground referred rising voltage at the (-) input of the comparator. When this reaches the threshold voltage (Vref), the comparator output switches low and MN turns off. The comparator output also drives another NMOS switch, which bypasses

internal resistor R3 to provide a controlled amount of hysteresis. The hysteresis is set by R3 to be nominally 15% of VADJ.

When MN is off, the current in L1 continues to flow via D1 and the LED(s) back to VIN. The current decays at a rate determined by the LED(s) and diode forward voltages to produce a falling voltage at the input of the comparator. When this voltage returns to VADJ, the comparator output switches high again. This cycle of events repeats, with the comparator input ramping between limits of  $Vref \pm 15\%$ .

### **Switching Thresholds**

With VADJ = VREF, the ratios of R1, R2 and R3 define an average VSENSE switching threshold of 100mV (measured on the ISENSE pin with respect to VIN). The average output current IOUTnom is then defined by this voltage and RS according to:

IOUTnom = 100mV/RS

Nominal ripple current is  $\pm 15$ mV/RS

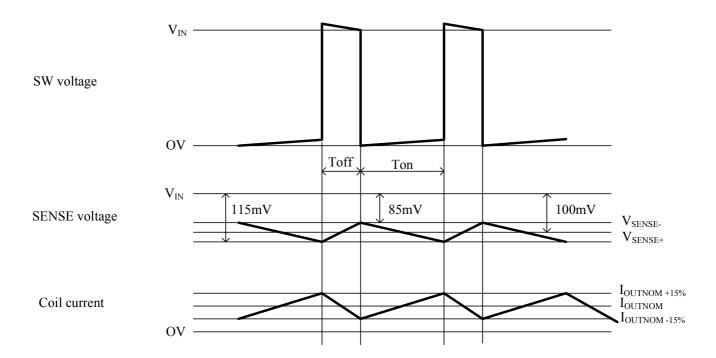
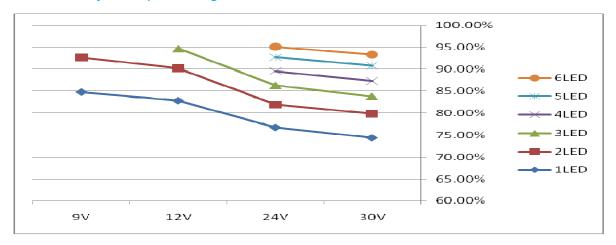


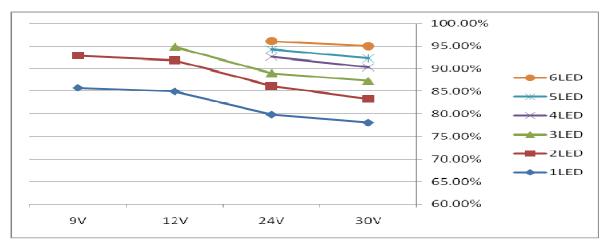
Figure 1-Operating waveforms

## **Typical Performance Characteristics**

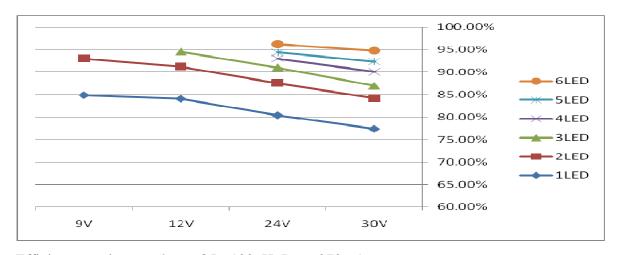
#### 1. Efficiency vs. Input Voltage at Various LED Cascaded Number



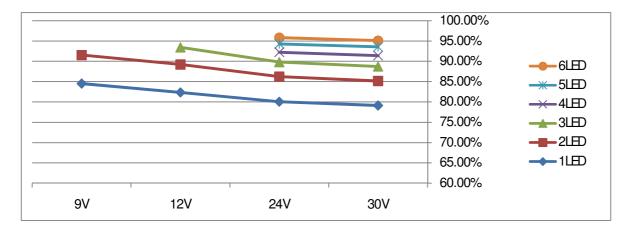
Efficiency vs. input voltage @L=22uH, I<sub>OUT</sub>=370mA



Efficiency vs. input voltage @L=68uH, I<sub>OUT</sub>=370mA

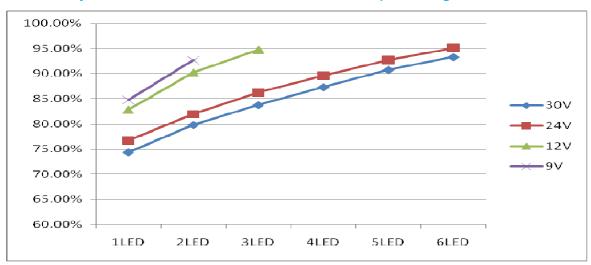


Efficiency vs. input voltage @L=100uH, I<sub>OUT</sub>=370mA

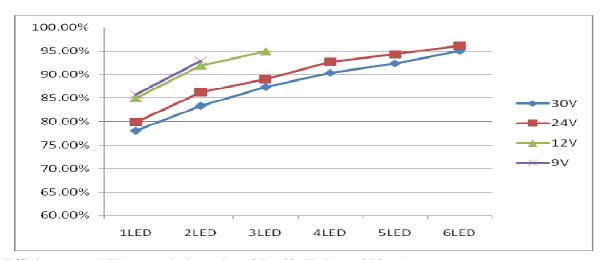


Efficiency vs. input voltage @L=68uH, I<sub>OUT</sub>=770mA

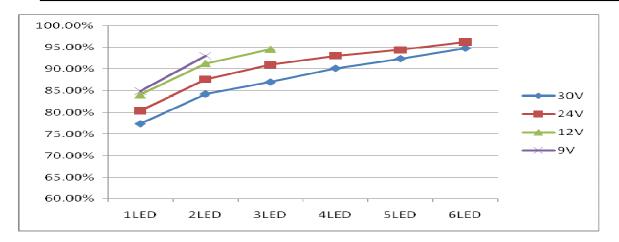
#### 2. Efficiency vs. LED Cascaded Number at Various Input Voltage



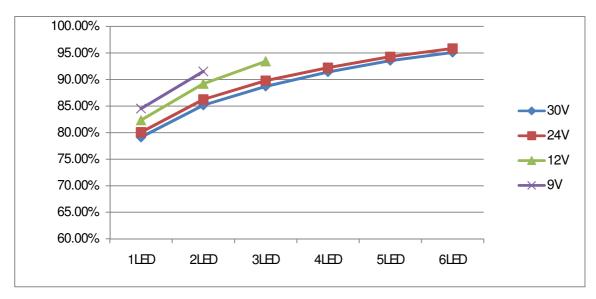
Efficiency vs. LED cascaded number @L=22uH, I<sub>OUT</sub>=370mA



Efficiency vs. LED cascaded number @L=68uH, I<sub>OUT</sub>=370mA

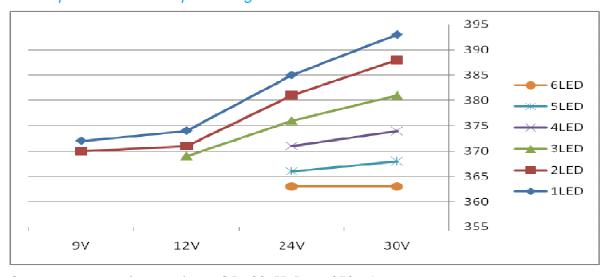


Efficiency vs. LED cascaded number @L=100uH, I<sub>OUT</sub>=370mA

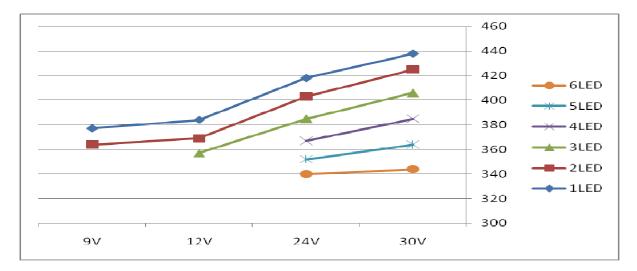


Efficiency vs. LED cascaded number @L=68uH, I<sub>OUT</sub>=770mA

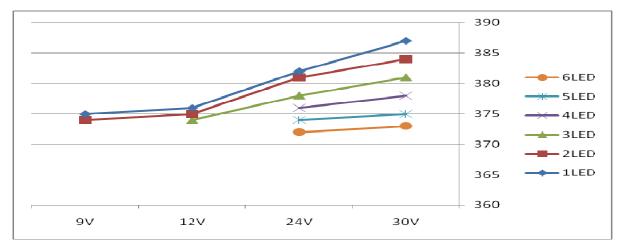
#### 3. Output Current vs. Input Voltage at Various LED Cascaded Number



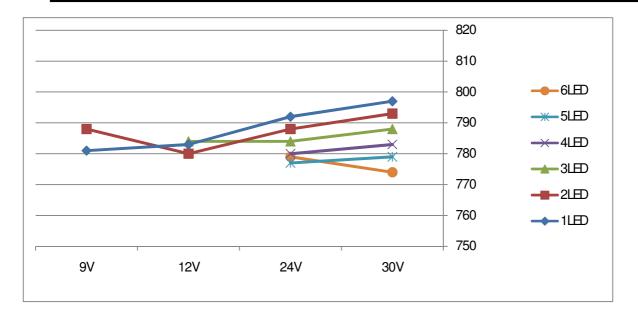
Output current vs. input voltage @L=22uH, I<sub>OUT</sub>=370mA



Output current vs. input voltage @L=68uH,  $I_{OUT}$ =370mA

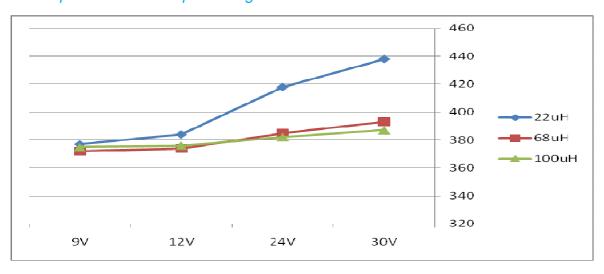


Output current vs. input voltage @L=100uH, I<sub>OUT</sub>=370mA

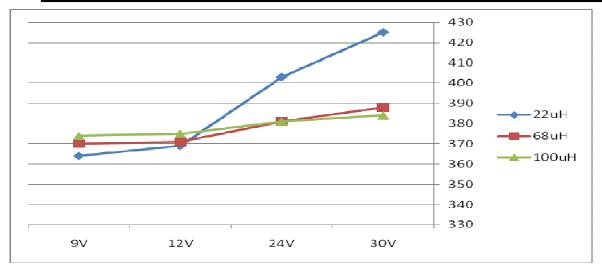


Output current vs. input voltage @L=68uH,  $I_{OUT}$ =770mA

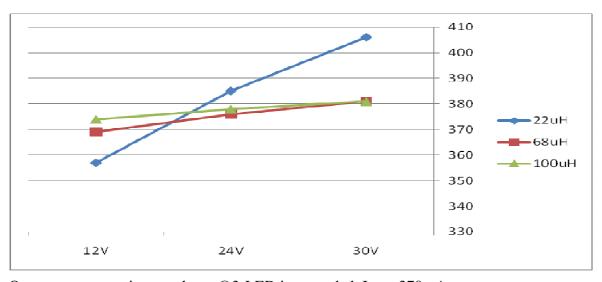
### 4. Output Currnet vs. Input Voltage at Various Inductor



Output current vs. input voltage @1-LED in cascaded, I<sub>OUT</sub>=370mA

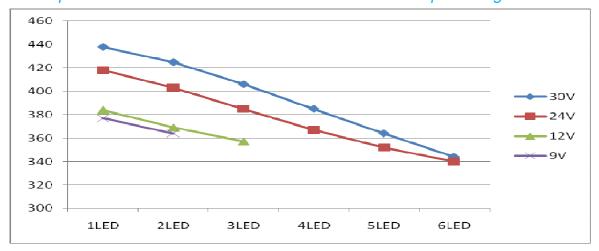


Output current vs. input voltage @2-LED in cascaded, I<sub>OUT</sub>=370mA

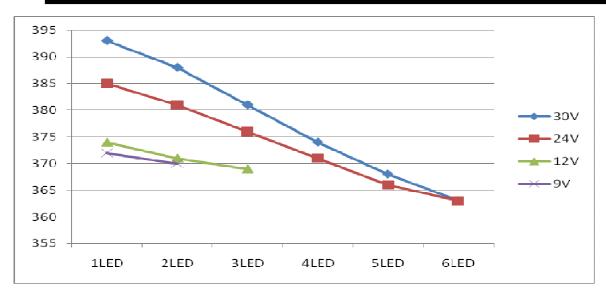


Output current vs. input voltage @3-LED in cascaded, I<sub>OUT</sub>=370mA

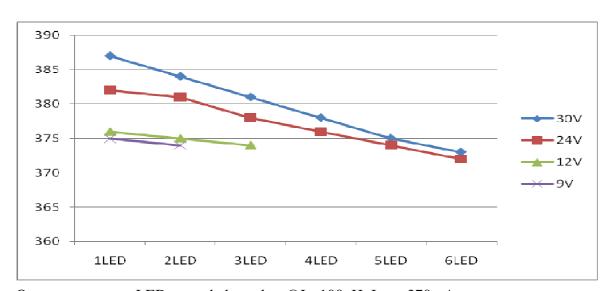
#### 5. Output Current vs. LED Cascaded Number at Various Input Voltage



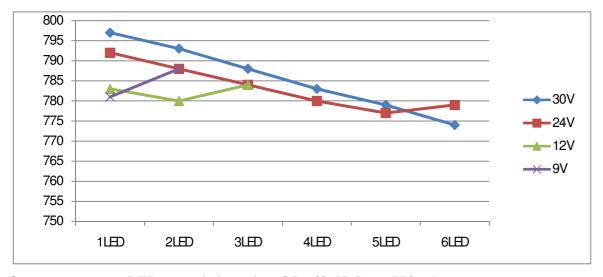
Output current vs. LED cascaded number @L=22uH, I<sub>OUT</sub>=370mA



Output current vs. LED cascaded number @L=68uH,  $I_{OUT}$ =370mA

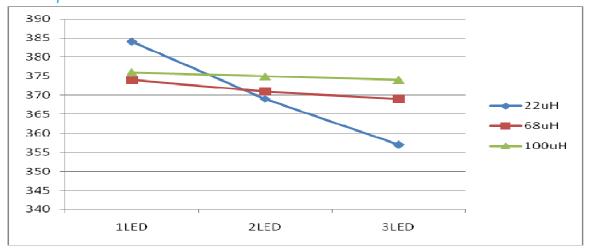


Output current vs. LED cascaded number @L=100uH,  $I_{OUT}$ =370mA

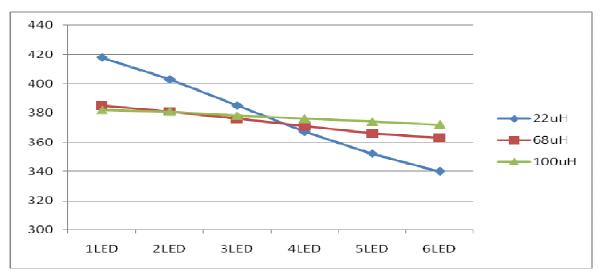


Output current vs. LED cascaded number @L=68uH, I<sub>OUT</sub>=770mA

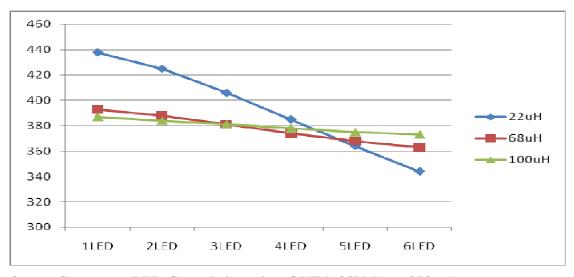
### 6. Output Current vs. LED Cascaded number at Various Inductor



Output Current vs. LED Cascaded number @VIN=12V, I<sub>OUT</sub>=370mA

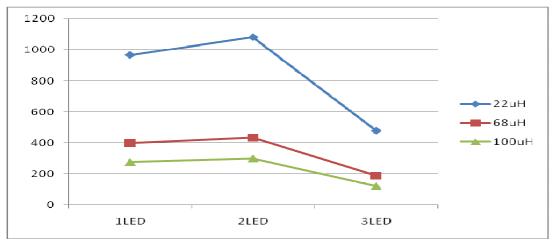


Output Current vs. LED Cascaded number @VIN=24V, I<sub>OUT</sub>=370mA

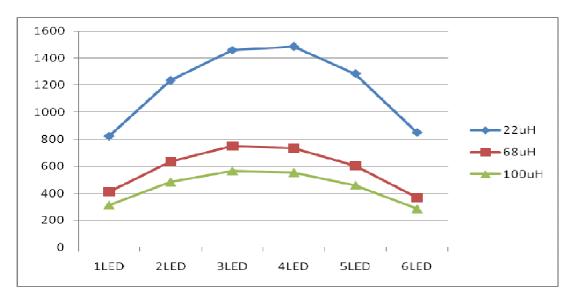


Output Current vs. LED Cascaded number @VIN=30V, I<sub>OUT</sub>=370mA

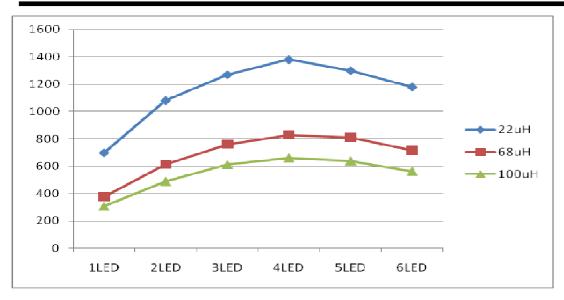
### 7. Switching Frequency vs. LED Cascaded Number at Various Inductor



Switching Frequency vs. LED Cascaded Number @VIN=12V, I<sub>OUT</sub>=370mA

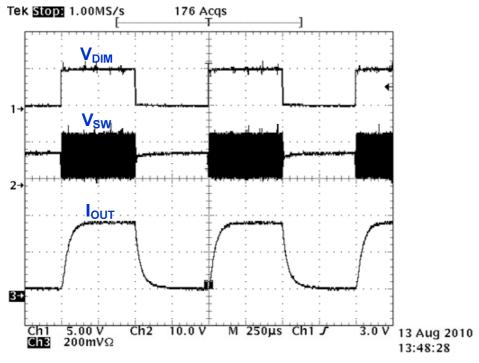


Switching Frequency vs. LED Cascaded Number @VIN=24V, I<sub>OUT</sub>=370mA

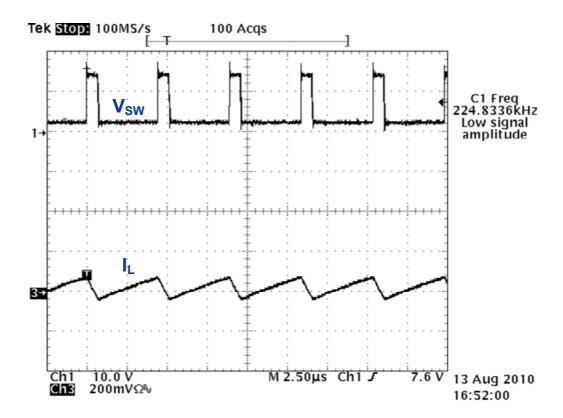


Switching Frequency vs. LED Cascaded Number @VIN=30V, I<sub>OUT</sub>=370mA

### 8. Dimming and switching waveforms



Dimming waveform( $V_{IN}$ =12V,  $R_{SEN}$ =0.27  $\Omega$ , 3-LED)



Switching waveform( $V_{IN}=12V$ ,  $R_{SEN}=0.27 \Omega$ , 3-LED)

### **Application Notes**

## .Setting nominal average output current with external resistor RS

The nominal average output current in the LED(s) is determined by the value of the external current sense resistor (RS) connected between VIN and Iout and is given by:

IOUTnom = 0.1/Rs [for Rs  $\geq$  0.1 $\Omega$ ] Nominal ripple current is  $\pm 15$ mV/Rs

The table below gives values of nominal average output current for several preferred values of current setting resistor (RS) in the typical application circuit shown on page 1:

$RS(\Omega)$	Nominal average output current (mA)
0.1	1000
0.13	760
0.15	667

### **Dimming**

A Pulse Width Modulated (PWM) signal with duty cycle DPWM can be applied to the DIM pin ., A logic low (below 0.5V) at DIM will disable the internal MOSFET and turn off the current Flow to the LED array . An internal pull-high circuit ensures that The SCT2932 is ON when DIM pin is unconnected .

#### . Open / short circuit LED protection

```
When any LED is open - circuit , the output current will be turned off .

When any LED is short - circuit , the output current will be limited to its preset value .
```

#### . Over Temperature protection

When the junction temperature over range . SCT2932 will turn off output Current .

### .Minimum Input Voltage

The Minimum Input Voltage is the sum of the voltage drops on  $R_{SEN}$  ,  $\;\;DCR$  of L1 ,  $Rds_{(ON)}\;\;$  of Internal MOS switch  $\;$  and the total forward voltage of LEDS  $\;\;V_{LED}\;\;$  .  $Vin=V_{RS}+V_{LED}+V_{L1}+V_{SW}\;.$ 

### **Design Consideration:**

### .Switching Frequency

For better output current accuracy, the switching frequency should be determined by Minimum on/off time SW waveform.

```
F_{SW=(1-D)/T_{OFF,MIN}} \ , \ \ when the duty cycle is large than 0.5 \qquad (D=\ \ Vout \ \ /\ Vin) or F_{SW=D/T_{ON,,MIN}} \ , \ \ when the duty cycle is \ \ smaller \ \ than 0.5
```

The switching frequency is related to efficiency (better at low frequency), the size/cost Of components, and the amplitude of output ripple voltage and current (smaller at high frequency). The slower switching frequency comes from the large value of inductor. In many applications, the

Sensitivity of EMI limits the switching frequency. The switching frequency can be ranged from 40Khz To 1.0Mhz.

#### . LED Ripple Current

A LED constant current driver , is designed to control the current through the cascaded LED , instead of the voltage across it . Higher LED ripple current allows the use of smaller inductance , smaller output capacitance and even without an output capacitor . The advantages of higher LED ripple current are to minimize PCB size and reduce cost because of no output capacitor . Lower LED ripple current requires large induce and output capacitor . The advantages of lower LED ripple Current are to extend LED life time and to reduce heating of LED . The recommended ripple current is From 5 % to 20% of normal LED output current .

### **Capacitor Selection**

A low ESR capacitor should be used for input decoupling, as the ESR of this capacitor appears in series with the supply source impedance and lowers overall efficiency. This capacitor has to supply the relatively high peak current to the coil and smooth the current ripple on the input supply.

A minimum value of 4.7uF is acceptable if the input source is close to the device, but higher values will improve performance at lower input voltages, especially when the source impedance is high. The input capacitor should be placed as close as possible to the IC. For maximum stability over temperature and voltage, capacitors with X7R, X5R, or better dielectric are recommended. Capacitors with Y5V dielectric are not suitable for decoupling in this application and should **NOT** be used . A suitable Murata capacitor would be GRM42-2X7R475K-50.

#### **Inductor Selection**

The inductance is determined by two factors: the switching frequency and the inductor ripple Current. The calculation of the inductance, L1, can be described as

L1 > (VIN-VOUT-VSEN-(Rds(ON)x IOUT))x D/(  $f_{swx} \triangle IL$ )

Higher values of inductance are recommended at higher supply voltages in order to minimize errors due to switching delays, which result in increased ripple and lower efficiency. Higher values of inductance also result in a smaller change in output current over the supply voltage range. (See graphs). The inductor should be mounted as close to the device as possible with low resistance connections to the SW and  $V_{IN}$  pins.

The chosen coil should have a saturation current higher than the peak output current and a

continuous current rating above the required mean output current.

The inductor value should be chosen to maintain operating duty cycle and switch 'on'/'off' times within the specified limits over the supply voltage and load current range.

```
Switch on time Ton = L\Delta I/(V_{IN}-V_{LED}-I_{avg}(Rs+rL+Rsw)) Toff = L\Delta I/(V_{LED}+V_{D}+I_{avg}(Rs+rL)) Where L \text{ is the coil inductance} rL \text{ is the coil resistance} Rs \text{ is the current sense resistance} Iavg \text{ is the required LED current} \Delta I \text{ is the coil peak-peak ripple current} \quad \{\text{Internally set to 0.3 x Iavg}\} V_{IN} \text{ is the supply voltage} V_{LED} \text{ is the total LED forward voltage} Rsw \text{ is the switch resistance}
```

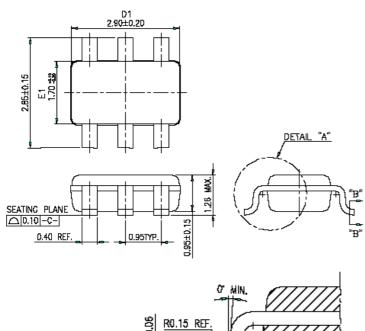
V<sub>D</sub> is the diode forward voltage at the required load current

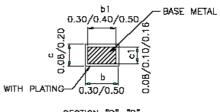
#### **Diode Selection:**

For maximum efficiency and performance, the rectifier (D1) should be a fast low capacitance Schottky diode with low reverse leakage at the maximum operating voltage and temperature. They also provide better efficiency than silicon diodes, due to a combination of lower forward voltage and reduced recovery time. It is important to select parts with a peak current rating above the peak coil current and a continuous current rating higher than the maximum output load current. It is very important to consider the reverse leakage of the diode when operating above 85°C. Excess leakage will increase the power dissipation in the device and if close to the load may create a thermal runaway condition. The higher forward voltage and overshoot due to reverse recovery time in silicon diodes will increase the peak voltage on the SW output. If a silicon diode is used, care should be taken to ensure that the total voltage appearing on the SW pin including supply ripple, does not exceed the specified maximum value.

## **Package Information**

## **SOT23-6** (SCT2932B)





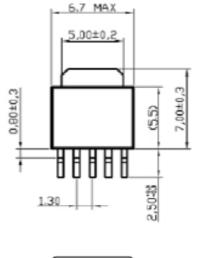
#### SECTION "B"-"B"

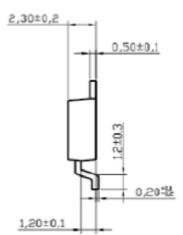
#### NOTES:

- 1.DIMENSION D1 & E1 DOES NOT INCLUDE MOLD PROTRUSION.
- 2.COPLANARITY OF ALL LEADS SHALL BE (BEFORE TEST) 0.1 MAX. FROM THE SEATING PLANE. UNLESS OTHERWISE SPECIFIED.
- 3.GENERAL PHYSICAL DUTLINE SPEC IS REFER TO TMC'S FINAL VISUAL INSPECTION SPEC UNLESS OTHERWISE SPECIFIED.

DETAIL "A" (S=32:1)

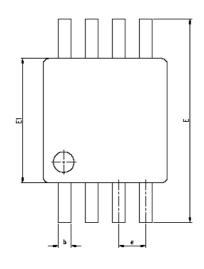
## TO252-5(SCT2932C)

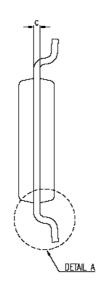


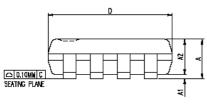


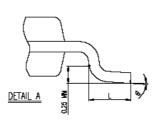


## MSOP8(SCT2932D)









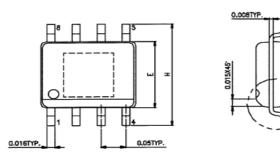
SYMBOL	DIMEN	ision II	MM /	DIMEN	SION IN	INCH
SIMOUL	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.81	1.02	1.10	0.032	0.040	D.043
A1	0.05		0.15	0.002		0.006
A2	0.76	88.0	D.95	0.030	0.034	0.037
b	0.28	0.30	0.38	0.011	0.012	0.015
C	0.13	0.15	0.23	0.005	0.006	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	4.75	4.90	5.05	0.187	0.193	0.199
E1	2.90	3.00	3.10	0.114	0.118	D.122
ę	0.	0.65 BASIC			26 BAS	IC
L	0.40	0.55	0.70	0.016	0.022	0.028
0	9	3"	б	0,	3*	6
JEDEC						

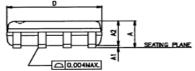
\*NOTES : DIMENSION " D " DOES NOT INCLUDE MOLD PROTRUSIONS OR CATE BURRS. MOLD PROTRUSIONS AND CATE BURRS SHALL NOT EXCEED

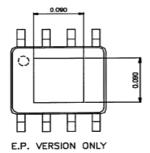
COLOG INCH (0.15 MM) PER SIDE.

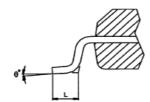
DIMENSION " E1 " DOES NOT INCLUDE WOLD PROTRUSIONS
MOLD PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.25 MM) PER SIDE .

# SOP8 (SCT2932E)









SYMBOLS	MIN.	MAX.
Α	0.053	0.069
A1	0.004	0.010
A2	_	0.059
D	0.189	0.196
E	0.150	0.157
Н	0.228	0.244
L	0.016	0.050
θ°	0	8

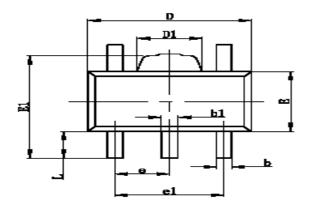
UNIT: INCH

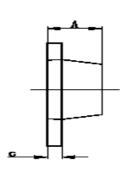
#### NOTES:

1.JEDEC OUTLINE: MS-012 AA / E.P. VERSION: N/A
2.DIMENSIONS "D" DOES NOT INCLUDE MOLD FLASH,
PROTRUSIONS OR GATE BURRS MOLD FLASH, PROTRUSIONS
AND GATE BURRS SHALL NOT EXCEED .15mm (.006in)
PER SIDE.

3.DIMENSIONS "E" DOES NOT INCLUDE INTER—LEAD FLASH, OR PROTRUSIONS. INTER—LEAD FLASH AND PROTRUSIONS SHALL NOT EXCEED .25mm (.010in) PER SIDE.

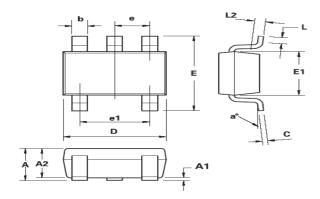
# SOT89-5(SCT2932F)





Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1.400	1.600	0.055	0.063	
b	0.320	0.520	0.013	0.020	
b1	0.360	0.560	0.014	0.022	
c	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.400	1.800	0.055	0.071	
E	2.300	2.600	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
e	1.500TYP 0.060TYP		OTYP		
e1	2.900	3.100	0.114	0.122	
L	0.900	1.100	0.035	0.043	

## **SOT23-5** (SCT2932J)



DIM	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
Α	-	1.00	-	0.0393	
A1	0.01	0.10	0.0003	0.0039	
A2	0.84	0.90	0.0330	0.0354	
b	0.30	0.45	0.0118	0.0177	
С	0.12	0.20	0.0047	0.0078	
D	2.90 BSC		0.114 BSC		
E	2.80 BSC		0.110 BSC		
E1	1.60 BSC		0.062 BSC		
е	0.95 BSC		0.037	4 BSC	
e1	1.90 BSC		0.0748 BSC		
L	0.30	0.50	0.0118	0.0196	
L2	0.25 BSC		0.010	BSC	
a°	<b>4</b> °	12°	4°	12°	

Information provided by StarChips Technology is believed to be accurate and reliable. Application circuits shown, if any, are typical examples illustrating the operation of the devices. Starchips can not assume responsibility and any problem raising out of the use of the circuits. Starchips reserves the right to change product specification without prior notice.

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